

IN THE UNITED STATE PATENT AND TRADEMARK OFFICE

In re Patent application of :

[inventor] :

[Serial No.] :

[Filed] :

[TITLE OF THE INVENTION]

**SUBMISSION OF ENGLISH-LANGUAGE TRANSLATION  
OF FOREIGN-LANGUAGE PROVISIONAL APPLICATION**

Honorable Commissioner For Patents  
Washington, D.C. 20231

Sir:

I, Yukie SATO, declare and say:  
(print name of translator)

that I am conversant in both the Japanese and English languages;

that I am presently engaged as a translator in these languages;

that the attached document represents an accurate English-language translation  
of the U.S Provisional Application Serial [60/441354] filed [September 27, 2002].

Signed this 1st day of August, 2003.

Yukie Sato  
(signature of translator)

## SURFACE ACOUSTIC WAVE FILTER WITH ATTENUATION POLES

## BACKGROUND OF THE INVENTION

The present invention relates to a band-pass filter of  
5 a ladder type configuration using a surface acoustic wave (SAW)  
resonator in small-sized mobile communication devices such as  
mobile telephones, particularly to a SAW filter with attenuation  
poles having high attenuation in an attenuation band and low  
insertion loss in a pass band.

10 In recent years, mobile communication device terminals  
such as small-sized, lightweight mobile telephones have been  
developed rapidly. In accordance with this, the realization  
of reduction in size and of high performance in components to  
be used is being conducted. In response to this, RF (radio  
15 frequency band) components using a SAW filter are developed  
and used. Particularly, the SAW filter is developed actively  
to partly become commercially available because it is a device  
that greatly contributes to the realization of reduction in  
size of RF parts.

20 In order to enhance the performance of the mobile  
communication device terminals, a high-performance SAW filter  
is demanded which has lower insertion loss in a pass band and  
high attenuation in attenuation bands.

The high-performance SAW filter is used in components  
25 for branching, inputting and outputting signals in the mobile

communication device terminals.

A traditional ladder type SAW filter forming the high-performance SAW filter is described in Band pass filter with low loss using SAW resonators, Sato, et al., IEICE Ronbunshi A, vol. J76-A, No. 2, pp. 245-252 (1993).

In addition, an attenuation pole filter shown in Fig. 12 added with an attenuation pole inductance L (330) is used as a high-performance filter.

Fig. 12 is a circuit diagram illustrating that a two-port circuit 1 (380) of a traditional ladder type SAW filter formed of three series arms S1 (310), S2 (311) and S3 (312) and two shunt arms P1 (320) and P2 (321) is serially connected to a two-port circuit 2 (381) provided with an attenuation pole inductance L (330).

As described in JP-A-10-163808, in the SAW filter with attenuation poles shown in Fig. 12, attenuation poles are formed in an attenuation band on the high frequency side of the pass band by the attenuation pole inductance L (330), in addition to the characteristics of the traditional ladder type SAW filter. The attenuation poles can provide certain high attenuation characteristics in the attenuation characteristics on the high frequency side of the pass band.

#### SUMMARY OF THE INVENTION

In order to enhance the performance of the recent mobile

communication device terminals, a high-performance SAW filter is demanded which has lower insertion loss in a pass band and high attenuation in the attenuation band on the low frequency side of the pass band. The high performance SAW filter is being  
5 investigated with the use of traditional bonding wire, but satisfying characteristics are not obtained yet under present circumstances.

In the traditional mobile communication device terminals such as mobile telephones, a SAW filter with attenuation poles  
10 having certain high attenuation characteristics in the attenuation band on the high frequency side of a communication band is shown in Fig. 12.

On this account, the circuit shown in Fig. 12 is used when attenuation poles need to be formed in the attenuation  
15 band on the high frequency side, and the traditional bonding wire is used for the attenuation pole inductance  $L$  (330) shown in Fig. 12.

In this example, the traditional bonding wire is used as the inductance  $L$  to vary the frequency of the attenuation  
20 poles by this  $L$  value, and the characteristics are changed to realize certain high attenuation. However, satisfying characteristics cannot be obtained yet.

Furthermore, high attenuation characteristics are demanded to provide in the attenuation band on the low frequency  
25 side, and attenuation poles need to be formed in the band.

However, the traditional bonding wire is also used in the case.

As a SAW filter with attenuation poles responding to this, a film is used in which the attenuation pole frequency of the attenuation band on the low frequency side of the pass band is adjusted by using the traditional bonding wire of the shunt arms in the ladder type SAW filter. However, required characteristics are not satisfied in this case as well.

In the mobile communication device terminals such as mobile telephones, a SAW filter with attenuation poles is desired which has high attenuation characteristics in the attenuation bands on the low frequency side and the high frequency side of the pass band. As a SAW filter with attenuation poles responding to this, a SAW filter with attenuation poles is used in which the traditional bonding wire is used as the inductance, an attenuation pole frequency is formed in the attenuation band on the low frequency side of the pass band, and the attenuation pole frequency is varied to provide high attenuation in the filter characteristics. However, the required characteristics are not satisfied.

In view of the problems, an object of the invention is to provide a high-performance SAW filter having lower insertion loss in a pass band and high attenuation in an attenuation band on the low frequency side of the pass band.

The invention adapts the following schemes for solving the problems.

(1) In a surface acoustic wave filter with attenuation poles configured of a two-port circuit for filtering for forming a ladder type surface acoustic wave filter with a surface acoustic wave resonator; and a two-port circuit for impedance formed of an impedance serially connected, the impedance of the two-port circuit for impedance is configured so as to form an attenuation band of a predetermined width having a sufficient attenuation characteristic on a low frequency side of a pass band.

(2) In the surface acoustic wave filter with attenuation poles as in (1), the impedance of the two-port circuit for impedance is formed of a resistance and an inductance.

(3) In the surface acoustic wave filter with attenuation poles as in (1), the impedance of the two-port circuit for impedance is formed of an impedance of a bonding wire.

(4) In a surface acoustic wave filter with attenuation poles configured of a two-port circuit for filtering for forming a ladder type surface acoustic wave filter with a surface acoustic wave resonator; and a two-port circuit for impedance formed of an impedance serially connected, the two-port circuit for impedance is configured of a  $\pi$  type circuit formed of three impedances so as to form an attenuation band of a predetermined width having a sufficient attenuation characteristic on a low frequency side of a pass band.

(5) In the surface acoustic wave filter with attenuation poles as in (4), a bonding wire is used as the three impedances of

the two-port circuit for impedance.

(6) In the surface acoustic wave filter with attenuation poles as in (2), two bonding wires with three electrodes are used as the impedance of the two-port circuit for impedance.

5 (7) In the surface acoustic wave filter with attenuation poles as in (2), two bonding wires with three electrodes are used for the impedance of the two-port circuit for impedance, and a capacitance is connected in parallel to one of the bonding wires.

10 (8) In the surface acoustic wave filter with attenuation poles as in any one of (1) to (7), an inductance is set almost constant to 1 nH and a resistance is set to any given value ranging from 0.20 to 1.20  $\Omega$  in the impedance.

(9) In the surface acoustic wave filter with attenuation poles  
15 as in any one of (1) to (7), an inductance is set almost constant to 0.5 nH and a resistance is set to any given value ranging from 0.10 to 0.60  $\Omega$  in the impedance.

#### BRIEF DESCRIPTION OF THE DRAWINGS

20 The teachings of the invention can be readily understood by considering the following detailed description in conjunction with the accompanying drawings, in which:

Fig. 1 is a diagram illustrating the circuit configuration of a first embodiment according to the invention;

25 Fig. 2 is a diagram illustrating a lumped constant

equivalent circuit of Fig. 1 for describing the first embodiment according to the invention;

Fig. 3 is a diagram illustrating a half circuit of the lumped constant equivalent circuit shown in Fig. 2 for describing the relationship between the characteristics and component devices of the first embodiment according to the invention;

Fig. 4 is a lattice type equivalent circuit of the first embodiment according to the invention;

Fig. 5 is a schematic diagram illustrating a second embodiment according to the invention;

Fig. 6 is a schematic diagram illustrating Example 1 of attenuation pole impedance according to the invention;

Fig. 7 is a diagram illustrating an equivalent circuit of Example 1 of attenuation pole impedance according to the invention;

Fig. 8 is a schematic diagram illustrating Example 2 of attenuation pole impedance according to the invention;

Fig. 9 is a diagram illustrating an equivalent circuit of Example 2 of attenuation pole impedance according to the invention;

Fig. 10 is a graph summarizing the characteristics of Tables 2 and 4 of the invention;

Fig. 11 is a diagram illustrating 'attenuation width' of the invention; and

Fig. 12 is a diagram illustrating a circuit configuration



in which the two-port circuit 1 (380) of a ladder type SAW filter formed of three series arms S1 (310), S2 (311) and S3 (312) and two shunt arms P1 (320) and P2 (321) is serially connected to the two-port circuit 2 (381) provided with the attenuation pole inductance L (330).

#### DETAILED DESCRIPTION OF THE INVENTION

Embodiments of the invention will be described in detail based on the drawings.

10

##### First Embodiment

Fig. 1 is a diagram illustrating the circuit configuration of a first embodiment according to the invention.

The first embodiment is configured in which a two-port circuit for filtering 1 (180) formed of a ladder type SAW filter of two-stage  $\pi$  type is serially connected to a two-port circuit 2 (181) using an attenuation pole impedance  $Z_{11}$  (140) serially connecting a resistance  $R_{11}$  to an inductance  $X_{11}$ , as depicted by solid lines in Fig. 1.

More specifically, a series arm S1 (110) is serially connected between an input terminal IN (103) and an output terminal OUT (104), shunt arm P1 (120) and P2 (121) are connected in parallel to the both ends of the series arm S1 (110) for forming the ladder type SAW filter of two-stage  $\pi$  type.

The two-port circuit for impedance 2 (181) is formed of

theattenuationpoleimpedance  $Z_{11}$  (140). The impedance  $Z_{11}$  (140) is configured of  $R_{11} + jX_{11}$ .

The invention is characterized in that the two-port circuit for impedance 2 (181) is configured in which the pole  
5 frequency of the attenuation band on the low frequency side can be varied by the real part  $R_{11}$  and the imaginary part  $X_{11}$  of the attenuation pole impedance  $Z_{11}$ .

Fig. 2 is a diagram illustrating a lumped constant equivalent circuit of Fig. 1 for describing the first embodiment  
10 according to the invention.

Fig. 3 is a diagram illustrating a half circuit of the lumped constant equivalent circuit shown in Fig. 2 for describing the relationship between the characteristics and component devices of the first embodiment according to the invention.  
15 The lumped constant equivalent circuit shown in Fig. 2 is configured in which a two-port circuit of a  $\pi$  type filter formed of a series arm  $S1$  (410) having an impedance  $2Z_{S11}$ , and shunt arms  $P1$  (420) and  $P2$  (421), each having an impedance  $Z_{F1}$ , is serially connected to a two-port circuit formed of an impedance  
20  $Z_{11}$  (440) having  $2R_{11} + j2X_{11}$ .

In the half equivalent circuit shown in Fig. 3, a series arm  $Z_{S11}$  (510) is connected between an input terminal  $IN$  (560) and a terminal  $M2$  (570), a shunt arm (520) having an impedance  $Z_{F1}$  and an impedance (540) having  $R_{11} + jX_{11}$  are serially connected  
25 between the input terminal  $IN$  (560) and an input terminal  $E1$

(561), and a node of the shunt arm  $ZF_1$  (520) and the impedance  $Z_{11}$  (540) is connected to a terminal M3 (572).

In Fig. 3, suppose an input impedance is  $Z_1$  where the terminal M2 (570), the terminal M3 (572) and a terminal E2 (571) are opened, and an input impedance is  $Z_2$  where the terminal M2 (570), the terminal M3 (572) and the terminal E2 (571) are short-circuited,  $Z_1$  and  $Z_2$  are given by Equation (1) and Equation (2), respectively.

$$Z_2 = ZF_1 + R_{11} + jX_{11} \quad (1)$$

$$10 \quad Z_1 = ZF_1 * ZS_1 / (ZF_1 + ZS_1) \quad (2)$$

Fig. 4 is a lattice type equivalent circuit of the first embodiment according to the invention.

The characteristics of the first embodiment can be evaluated by converting the circuit shown in Fig. 1 to the lattice type circuit shown in Fig. 4 in equivalent circuit with  $Z_1$  and  $Z_2$ . F matrix (four-terminal matrix [F]) in this case can be given by Equation (3).

$$\begin{bmatrix} A & B \\ C & D \end{bmatrix} = \frac{1}{Z_2 - Z_1} \begin{bmatrix} Z_1 + Z_2 & 2Z_1 Z_2 \\ 2 & Z_1 + Z_2 \end{bmatrix} \quad (3)$$

Accordingly, since a coefficient  $S$  of operating transmission is  $S = (A + B + C + D)/2$  from Equation (3), it is evaluated by using Equation (4).

$$S = \frac{(Z_1 + Z_2) + Z_1 Z_2 + 1}{Z_2 - Z_1} \quad (4)$$

An attenuation characteristic  $\alpha(\omega)$  is given by Equation

(5).

$$\alpha(\omega) = -20 \cdot \log |(S)| \quad (\text{dB}) \quad (5)$$

From Equations (4) and (5), the attenuation pole frequency of the attenuation characteristic  $\alpha(\omega)$  is the following case.

5 In the case of the traditional ladder type SAW filter, it is known that attenuation poles are formed under the conditions that the impedances  $Z_2$  and  $Z_1$  are infinite and zero.

In addition to the conditions, the invention is characterized in that the attenuation pole frequency is formed also in the case where  $Z_2 = Z_1$  and the attenuation pole impedance  $Z_{11}$  (140) has the real part and the imaginary part.

In the meantime, the traditional bonding wire only has an inductance and the frequency is formed in the imaginary part alone. More specifically, in the invention, the attenuation characteristic can be changed also in the real part.

Hereinafter, a SAW filter for Cdma-One will be exemplified to describe the usability of the invention.

Table 1 shows the configuration of resonators, the series arm and the shunt arms shown in Fig. 1.

Table 1

Configuration of resonators	Series arm S1 (110)	Shunt arm P1 (120)	Shunt arm P2 (121)
Intersection length ( $\mu\text{m}$ )	60	70	70
Logarithm	60	80	80

Table 2 shows the usability of the invention.

Table 2

1-1. Attenuation pole inductance L is 1 (nH)

19.0 dB Width	4	14	15.8	16.1	16.2	16.1	15.9	15.5	15
R (OHM)	4.00	2.00	1.20	0.80	0.60	0.40	0.20	0.12	0.0004
L (nH)	1	1	1	1	1	1	1	1	1
Q	1	2.5	5	7.5	10	15	20	50	1000

5 1-2. Attenuation pole inductance L is 0.5 (nH)

24.0 dB Width	3	8.5	9.2	9.2	9	8.9	8.8	8.5	8
R (OHM)	2.00	1.00	0.60	0.40	0.30	0.20	0.10	0.06	0.0002
L (nH)	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
Q	1	2.5	5	7.5	10	15	20	50	1000

Traditionally, as a scheme to obtain high attenuation characteristics, the response is that the bonding wire is used as the attenuation pole inductance L to form attenuation poles in the attenuation band as described in the publicly known document.

More specifically, the traditional bonding wire in which the resistance value can be ignored and only the inductance acts as impedance is used to form attenuation poles in the attenuation band.

In the meantime, as shown in Table 2, the invention can obtain the high attenuation characteristics in which at least a resistance component is increased in addition to the impedance of the traditional bonding wire and thus the attenuation pole

frequency and the attenuation characteristic can be varied without changing the pass band characteristics.

The bonding wire of the invention is a line that at least a resistance component is increased in addition to the impedance  
5 of the traditional bonding wire. The impedances are set to the relationship described below.

Hereinafter, the bonding wire of the invention will first be described based on Figs. 6 to 9.

Fig. 6 is a schematic diagram illustrating Example 1 of  
10 attenuation pole impedance according to the invention.

Fig. 7 is a diagram illustrating an equivalent circuit of Example 1 of attenuation pole impedance according to the invention.

Fig. 8 is a schematic diagram illustrating Example 2 of  
15 attenuation pole impedance according to the invention.

Fig. 9 is a diagram illustrating an equivalent circuit of Example 2 of attenuation pole impedance according to the invention.

Fig. 6 is an example of attenuation pole impedance using  
20 the bonding wire of the invention. The bonding wire of the invention is formed to be a connecting wire 102, and an electrode 1 on a piezoelectric substrate 100 side is connected to an electrode 2 on a package 101 side.

Fig. 7 depicts an equivalent circuit of Fig. 6, in which  
25 an electrode 112 (110) connected to the electrode 1 on the

piezoelectric substrate 100 side is connected to an electrode 113 (111) connected to the electrode 2 on a package 101 side by a series circuit formed of a resistance  $R_{11}$  and an inductance  $L_{11}$ . More specifically, it shows that the impedance of the connecting wire 102 formed of the bonding wire of the invention is  $R_{11} + j\omega L_{11}$ .

Moreover, an example that the reactive component of impedance can be adjusted is shown in Fig. 8. The bonding wire of the invention is formed to be a connecting wire (1) 126 and a connecting wire (2) 127 to connect an electrode (1) on a piezoelectric substrate 120 side, an electrode (2) on a package 121 side and an electrode (3) on a package 122 side to each other. Furthermore, a capacitance substrate 123 for adjusting the reactive component is connected between the electrode (2) on the package 121 side and the electrode (3) on the package 122 side through normal connecting wires (C1) 124 and (C2) 125 which can ignore resistance values and are unrelated to the bonding wire of the invention.

Fig. 9 depicts an equivalent circuit of Fig. 8, in which an electrode 133 (130) connected to the electrode 1 on the piezoelectric substrate 120 side is connected to an electrode 134 (131) connected to the electrode 2 on the package 121 side by a series circuit formed of a resistance  $R_{11}$  and an inductance  $L_{11}$ . An equivalent circuit is formed in which the electrode 134 (131) connected to the electrode 2 on the package 121 side

is connected to an electrode 135 (132) connected to the electrode 3 on the package 122 by a series circuit formed of a resistance  $R_{12}$  and an inductance  $L_{12}$ . Similarly, an equivalent circuit is formed in which the electrode 134 (131) connected to the electrode 2 on the package 121 side and the electrode 135 (132) connected to the electrode 3 on the package 122 are connected to a capacitance  $C_{12}$  through normal connecting wires that can ignore resistance values. More specifically, the equivalent circuit is formed in which the electrode 133 (130) is connected to the electrode 134 (131) by the circuit having  $R_{11} + j\omega L_{11}$  and the electrode 134 (131) is connected to the electrode 135 (132) by the circuit having  $R_{12} + j\omega L_{12}$  and the circuit having  $1/j\omega C_{12}$ .

As described above, the attenuation pole impedance of the invention is configured as described with Figs. 6 to 9.

Table 2-1-1 shows the value of attenuation width (MHz) where the attenuation value of the attenuation band on the low frequency side of the pass band is 19.0 (dB) when the attenuation pole impedance  $Z_{11}$  is almost constant to the inductance  $L$  nearly equal 1 (nH) and the resistance  $R$  is a parameter and shows the  $Q$  characteristic value of the SAW filter with attenuation poles.

Table 2-1-2 shows the value of attenuation width (MHz) where the attenuation value of the attenuation band on the low frequency side of the pass band is 24.0 (dB) when the attenuation pole impedance  $Z_{11}$  is almost constant to the inductance  $L$  nearly



equal 0.5 (nH) and the resistance R is a parameter and shows the Q characteristic value of the SAW filter with attenuation poles.

Fig. 11 is a diagram for describing the attenuation width  
5 of the invention.

In addition, as shown in Fig. 11, the 'attenuation width' is an interval that the attenuation value of the attenuation band on the low frequency side of the pass band continues at a predetermined value or below. 'Predetermined value' is the  
10 value that the attenuation value of the attenuation band on the low frequency side is sufficiently attenuated with respect to the attenuation value of the pass band in practice. Under the present circumstances, the tendency shows the characteristics that can provide sufficient attenuation width,  
15 not the characteristics that are greatly attenuated in a narrow range.

#### Range of Resistance in the First Embodiment

The attenuation value of the attenuation band on the low  
20 frequency side of the pass band and the value of attenuation width (MHz) are set to be sufficient values at practical levels. A preferable range of the resistance value to surely clear the conditions at that time is as follows:

- 1) The range of resistance where L is nearly equal 1 (nH)  
25 is 0.20 to 1.20 ( $\Omega$ ).

2) The range of resistance where  $L$  is nearly equal 0.5 (nH) is 0.10 to 0.60 ( $\Omega$ ).

#### Advantage of the First Embodiment

5 As described above, the first embodiment has high attenuation characteristics in the attenuation band on the low frequency side of the pass band.

The traditional response is that the bonding wire is used as the attenuation pole inductance  $L$  in order to realize high  
10 attenuation characteristics by providing attenuation poles in the attenuation band in the attenuation band on the low frequency side of the pass band, but satisfying characteristics are not obtained.

In the meantime, as compared with the characteristics  
15 of the traditional ladder type SAW filter, the first embodiment according to the invention can obtain required characteristics in which the impedance having the real part is used in the two-port circuit for forming the pole frequency and high attenuation characteristics are obtained by the real part of the resistance  
20 component along with the impedance such as the bonding wire.

#### Second Embodiment

Fig. 5 is a schematic diagram illustrating a second embodiment according to the invention.

25 In the second embodiment, a two-port circuit for filtering

1 (180) is configured of a ladder type SAW filter of two-stage  $\pi$  type having the same circuit configuration as that of the first embodiment, and a two-port circuit for impedance 2 (181) is configured of a  $\pi$  type circuit using three impedances. Each of three impedances  $Z_{21}$  (241),  $Z_{22}$  (242) and  $Z_{23}$  (243) is configured of a resistance  $R$  and an inductance  $X$ .

More specifically, the two-port circuit for filtering 1 (180) configures the  $\pi$  type circuit of one series arm  $S1$  (210) and two shunt arms  $P1$  (220) and  $P2$  (221).

10 The two-port circuit for impedance 2 (181) configures the  $\pi$  type circuit of an attenuation pole impedance  $Z_{21}$  (241) having  $R_1 + jX_1$ , an attenuation pole impedance  $Z_{22}$  (242) having  $R_2 + jX_2$  and an attenuation pole impedance  $Z_{23}$  (243) having  $R_3 + jX_3$ .

15 The invention is characterized in that high attenuation characteristics can be provided in the pole frequency of the attenuation band on the low frequency side by the real part  $R$  and the imaginary part  $X$  of the attenuation pole impedances  $Z_{21}$ ,  $Z_{22}$  and  $Z_{23}$ .

20 The configuration of each resonator of the second embodiment is the same as the configuration of the first embodiment, shown in Table 3.

Table 3

Configuration	series arm $S1$	shunt arm $P1$	shunt arm $P2$
---------------	-----------------	----------------	----------------

of resonators	(110)	(120)	(121)
Intersection length ( $\mu\text{m}$ )	60	70	70
Logarithm	80	80	80

$Z_1$  and  $Z_2$  in Equation (8) are given by Equations (6) and (7).

$$Z_2 = ZF_1 + R_{11} + jX_{11} \quad (6)$$

$$Z_1 = ZF_1 * (ZS_1 + Z_{ss}) / (ZF_1 + ZS_1 + Z_{33}) \quad (7)$$

where  $Z_{ss} = (R_1 + jX_1) * (R_2 + jX_2) / (R_1 + jX_1 + R_2 + jX_2)$ .

Accordingly, a coefficient  $S$  of operating transmission is evaluated by Equation (7) from Equation (6).

$$S = \frac{Z_1 + Z_2 + Z_1 Z_2 + 1}{Z_2 - Z_1} \quad (8)$$

The attenuation characteristic of the second embodiment can be determined by putting Equations (6) and (7) in Equation (8). More specifically, the difference from the first embodiment is in that Equations (6) and (7) are put in Equation (8) for determination because the  $\pi$  type circuit configuration is used in the two-port circuit 2. Accordingly, the pole frequency is a frequency that the denominator of Equation (8) is zero, and the attenuation characteristic becomes high attenuation characteristics, being different from traditional ones.

Hereinafter, the frequency band of the cdmaOne filter will be exemplified to describe the usability of the invention with reference to Table 4. Table 4 shows resonators, the series

arm and the shunt arms configuring the circuit shown in Fig.  
5.

The upper part of Table 4-2-1 shows the value of  
attenuation width (MHz) where the attenuation value of the low  
5 frequency side of the attenuation band of the pass band is 15.5  
(dB) when the attenuation pole impedances  $Z_{21}$ ,  $Z_{22}$  and  $Z_{23}$  are  
almost constant to the inductances L1 to L3 nearly equal 0.5  
(nH) and the resistance R is a parameter, and shows the Q  
characteristic value of the SAW filter with attenuation poles.

10 The lower part of Table 4-2-1 shows the value of  
attenuation width (MHz) where the attenuation value of the  
attenuation band on the low frequency side of the pass band  
is 22.0 (dB) when the attenuation pole impedances  $Z_{21}$ ,  $Z_{22}$  and  
 $Z_{23}$  are almost constant to the inductances L1 and L3 nearly equal  
15 0.5 (nH) and to the inductance L2 nearly equal 0.2 (nH) and  
the resistance R is a parameter, and shows the Q characteristic  
value of the SAW filter with attenuation poles.

The upper part of Table 4-2-2 shows the value of  
attenuation width (MHz) where the attenuation value of the  
20 attenuation band on the low frequency side of the pass band  
is 15.5 (dB) when the attenuation pole impedances  $Z_{21}$ ,  $Z_{22}$  and  
 $Z_{23}$  are almost constant to the inductances L1 to L3 nearly equal  
1.0 (nH) and the resistance R is a parameter, and shows the  
Q characteristic value of the SAW filter with attenuation poles.

25 The middle part of Table 4-2-2 shows the value of

attenuation width (MHz) where the attenuation value of the  
attenuation band on the low frequency side of the pass band  
is 24.1 (dB) when the attenuation pole impedances  $Z_{21}$ ,  $Z_{22}$  and  
 $Z_{23}$  are almost constant to the inductances  $L1$  and  $L3$  nearly equal  
5 1.0 (nH) and to the inductance  $L2$  nearly equal 0.2 (nH) and  
the resistance  $R$  is a parameter, and shows the  $Q$  characteristic  
value of the SAW filter with attenuation poles.

The lower part of Table 4-2-2 shows the value of  
attenuation width (MHz) where the attenuation value of the  
10 attenuation band on the low frequency side of the pass band  
is 17.2 (dB) when the attenuation pole impedances  $Z_{21}$ ,  $Z_{22}$  and  
 $Z_{23}$  are almost constant to the inductances  $L1$  and  $L3$  nearly equal  
1.0 (nH) and to the inductance  $L2$  nearly equal 0.5 (nH) and  
the resistance  $R$  is a parameter, and shows the  $Q$  characteristic  
15 value of the SAW filter with attenuation poles.

Table 4

2-1. Attenuation pole inductance  $L$  is 0.5 (nH)

15.5 Width	9.8	10.8	12.3	13.3	13.2	13.5	12	11
R (OHM)	2.00	1.00	0.60	0.40	0.30	0.20	0.10	0.01
L1, L3	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
L2	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
Q	1	2.5	5	7.5	10	15	20	1000

15.5 dB Width	7.5	9.2	10	10.7	10.7	11.3	10	8
R (OHM)	2.00	1.00	0.60	0.40	0.30	0.20	0.10	0.01
L1, L3	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
L2	0.2	0.2	0.2	0.2	0.2	0.2	0.2	0.2
Q	1	2.5	5	7.5	10	15	20	1000

## 2-2. Attenuation pole inductance L is 1.0 (nH)

15.5 dB Width	18.3	20.3	23.3	26	26.4	26.8	26.7	21.5
R (OHM)	4.00	2.00	1.20	0.80	0.60	0.40	0.20	0.01
L1, L3	1	1	1	1	1	1	1	1
L2	1	1	1	1	1	1	1	1
Q	1	2.5	5	7.5	10	15	20	1000

15.5 dB Width	4.4	6.6	8.3	8.7	8.8	8.9	8.7	6.5
R (OHM)	4.00	2.00	1.20	0.80	0.60	0.40	0.20	0.01
L1, L3	1	1	1	1	1	1	1	1
L2	0.2	0.2	0.2	0.2	0.2	0.2	0.2	0.2
Q	1	2.5	5	7.5	10	15	20	1000

15.5 dB Width	12.3	14.3	17.2	19.1	19.5	19.8	19.7	16
R (OHM)	4.00	2.00	1.20	0.80	0.60	0.40	0.20	0.01
L1, L3	1	1	1	1	1	1	1	1
L2	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
Q	1	2.5	5	7.5	10	15	20	1000

5

## Range of Resistance in the Second Embodiment

The attenuation value of the attenuation band on the low frequency side of the pass band and the value of attenuation width (MHz) are set to sufficient values at practical levels.

10 A preferable range of the resistance value to surely clear the conditions at that time is as follows:

1) The range of resistance is 0.20 to 1.20 ( $\Omega$ ) when L is nearly equal 1 (nH).

15 2) The range of resistance is 0.10 to 0.60 ( $\Omega$ ) when L is nearly equal 0.5 (nH).

Traditionally, as a scheme to obtain high attenuation characteristics, the response is that the bonding wire is used

as the attenuation pole inductance  $L$  to form attenuation poles in the attenuation band as described in the related document.

The second embodiment according to the invention can obtain high attenuation characteristics in which the resistance component is used in addition to the bonding wire and thus the attenuation pole frequency and the attenuation characteristic can be varied without changing the pass band characteristics. Particularly, the improvement in the attenuation characteristic is significant, allowing a bandwidth of 20 (dB) to be a broad band.

#### Relationship between the Attenuation Width and Resistance of the SAW Filter with Attenuation Poles

Fig. 10 is a graph summarizing the characteristics of Tables 2 and 4 of the invention.

Characteristic curve (1) depicts Table 2-1-1.

Characteristic curve (2) depicts Table 2-1-2.

Characteristic curve (3) depicts the upper part of Table 4-2-1.

Characteristic curve (4) depicts the lower part of Table 4-2-2.

Characteristic curve (5) depicts the upper part of Table 4-2-2.

Characteristic curve (6) depicts the middle part of Table 4-2-2.



Characteristic curve (7) depicts the lower part of Table 4-2-2.

Points a, a', b, b', c, c', d, d', e, e', f, f', g and g' of each of the characteristic curves mean 'a predetermined value' expressing the interval where the attenuation value of the attenuation band on the low frequency side of the pass band continues at a predetermined value or below, meaning an effective range including the preferable ranges described above.

The conditions for good items are that the range of resistance is 0.1 to 0.6 ( $\Omega$ ) when the attenuation pole inductance L is nearly equal 0.5 (nH).

The conditions for good items are that the range of resistance is 0.1 to 1.2 ( $\Omega$ ) when the attenuation pole inductance L is nearly equal 1.0 (nH).

The attenuation pole impedance tends to broaden the range of resistance as the value of inductance L is increased.

The relationship between the inductance and resistance can be selected based on these characteristic curves.

As described above, the invention has high attenuation characteristics in the attenuation band on the low frequency side of the pass band.

The invention can obtain required characteristics in which the impedance having the real part is used in the two-port circuit for forming the pole frequency and high attenuation characteristics are provided by the real part of the resistance

component along with impedance such as the bonding wire, as compared with the characteristics of the traditional ladder type SAW filter.

5

## ABSTRACT OF THE DISCLOSURE

A high-performance SAW filter is to be provided which has lower insertion loss in a pass band and high attenuation in an attenuation band on the low frequency side of the pass  
10 band. In a SAW filter with attenuation poles configured of a two-port circuit for filtering for forming a ladder type SAW filter using a SAW resonator and a two-port circuit for impedance formed of an impedance serially connected, the impedance of the two-port circuit for impedance is configured so as to form  
15 an attenuation band of a predetermined width having a sufficient attenuation characteristic on the low frequency side of a pass band.